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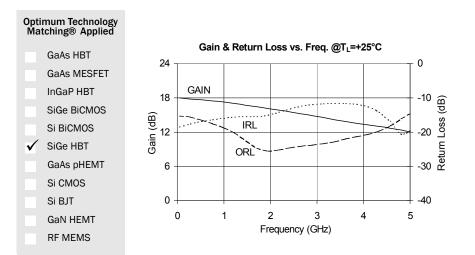
DC to 5000 MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER

Package: SOT-363



Product Description

The SGA2363Z is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high $F_{\rm T}$ and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.



Features

- High Gain: 16.1dB at 1950MHz
- Cascadable 50Ω
- Operates from Single Supply
- Low Thermal Resistance Package

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

Parameter	Specification			Linit	Condition
Parameter	Min.	Тур.	Max.	Unit	Condition
Small Signal Gain	15.8	17.5	19.3	dB	850MHz
		16.1		dB	1950MHz
		15.6		dB	2400MHz
Output Power at 1dB Compression		8.2		dBm	850MHz
		7.2		dBm	1950MHz
Output Third Intercept Point		19.4		dBm	850MHz
		19.0		dBm	1950MHz
Bandwidth Determined by Return Loss		5000		MHz	>10dB
Input Return Loss		15.1		dB	1950MHz
Output Return Loss		25.5		dB	1950MHz
Noise Figure		3.2		dB	1950MHz
Device Operating Voltage	2.4	2.7	3.0	V	
Device Operating Current	17	20	23	mA	
Thermal Resistance		255		°C/W	junction - lead

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Absolute Maximum Ratings

Parameter	Rating	Unit
Max Device Current (I _D)	40	mA
Max Device Voltage (V _D)	5	V
Max RF Input Power	+18	dBm
Max Junction Temp (T _J)	+150	°C
Operating Temp Range (T_L)	-40 to +85	°C
Max Storage Temp	+150	°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:

 $I_D V_D < (T_J - T_L) / R_{TH}$, j-I

Typical Performance at Key Operating Frequencies

Caution! ESD sensitive device.

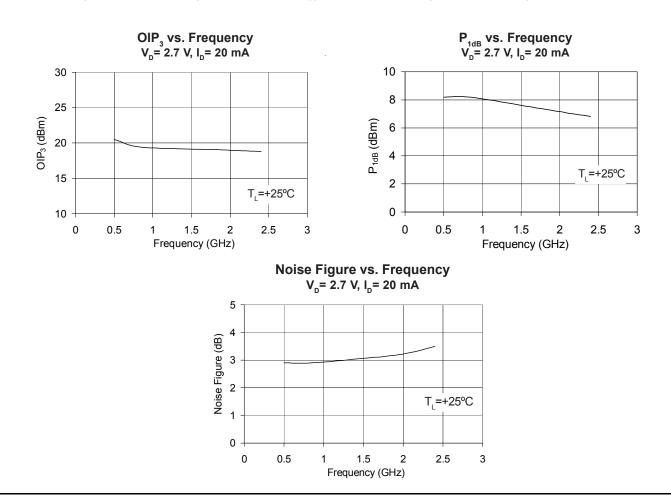
Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

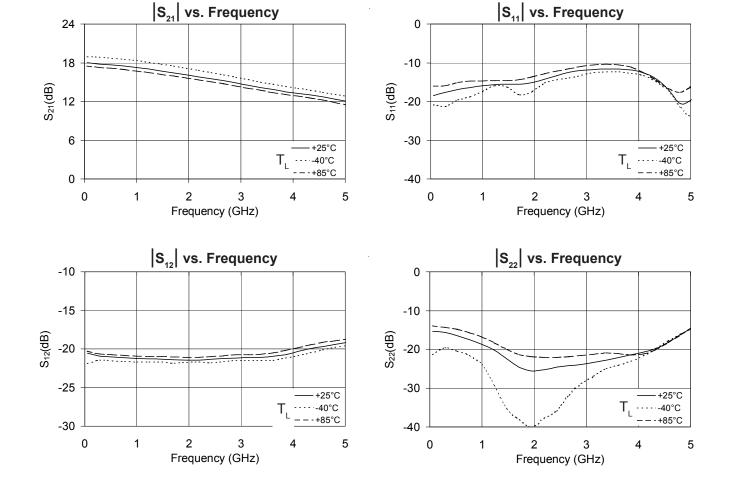
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Parameter	Unit	100 MHz	500 MHz	850 MHz	1950 MHz	2400MHz	3500 MHz
Small Signal Gain	dB	18.0	17.7	17.4	16.1	15.6	14.0
Output Third Order Intercept Point	dBm		20.5	19.4	19.0	18.8	
Output Power at 1dB Compression	dBm		8.2	8.2	7.2	6.8	
Input Return Loss	dB	18.2	17.0	16.2	15.1	13.3	11.6
Output Return Loss	dB	15.4	16.4	18.0	25.5	24.6	22.4
Reverse Isolation	dB	20.7	21.0	21.2	21.4	21.3	21.0
Noise Figure	dB		2.9	2.9	3.2	3.5	

Test Conditions: $V_S = 5V$, $I_D = 20$ mA Typ., OIP₃ Tone Spacing = 1 MHz, P_{OUT} per tone = -10 dBm, $R_{BIAS} = 140\Omega$, $T_L = 25$ °C, $Z_S = Z_L = 50\Omega$



Typical RF Performance Over Temperature (Bias: $V_D = 2.7 V$, $I_D = 20 \text{ mA}$ (Typ.))





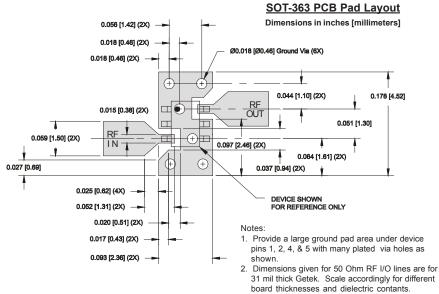
SGA2363Z

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Pin	Function	Description
3	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
1, 2, 4, 5	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
6	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper oper- ation.

SOT-363 PCB Pad Layout



We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick Getek with 1 ounce copper on both sides.

.014 [0.35] REF .051 [1.30] .026 [0.65] .051 [1.30] .017 [0.43] REF .051 [1.30] .049 [1.25] .083 [2.10] .049 [1.25] .083 [2.10] .010 [0.25] .006 [0.14]

SOT-363 Nominal Package Dimensions

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.002 [0.05]

2400

56 pF

22 pF

18 nH

8 V

270 Ω

3500

39 pF

15 pF

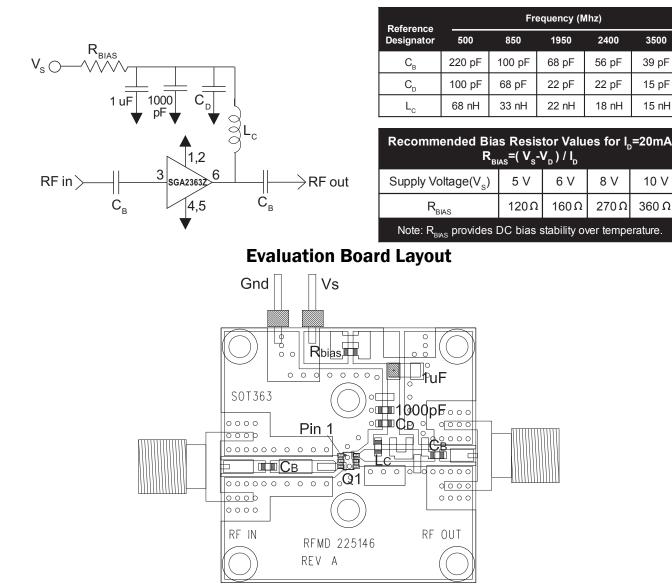
15 nH

10 V

360 Ω



Basic Application Circuit



Mounting Instructions:

1. Use a large droung pad area near device pins 1, 2, 4, and 5 with plated through-holes as shown.

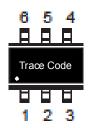
2. We recommend 1 or 2 ounces copper. Measurements for this data sheet were made on a 31mil thick FR-4 board with 1 ounce copper on both sides.



Part Identification Marking



Alternate Marking with Trace Code Only



Ordering Information

Ordering Code	Description
SGA2363Z	7" Reel with 3000 pieces
SGA2363ZSQ	Sample bag with 25 pieces
SGA2363ZSR	7" Reel with 100 pieces
SGA2363ZPCK1	850MHz, 5V Operation PCBA with 5-piece sample bag